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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/716,424	11/20/2003	Il-Young Kwon	P69289US0	6953
JACOBSON, PRICE, HOLMAN & STERN PROFESSIONAL LIMITED LIABILITY COMPANY 400 Seventh Street, N.W. Washington, DC 20004			EXAMINER	
			GARCIA, JOANNIE A	
			ART UNIT	PAPER NUMBER
			2823	
		DATE MAILED: 12/14/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
·	10/716,424	KWON, IL-YOUNG			
Office Action Summary	Examiner	Art Unit			
	Joannie A García	2823			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).					
Status	•				
1) Responsive to communication(s) filed on	<u> </u>				
2a) This action is FINAL . 2b) ⊠ Th	nis action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims					
4) Claim(s) 1-7 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 1 and 7 is/are rejected. 7) Claim(s) 2-6 is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement.					
Application Papers					
9) The specification is objected to by the Examination The drawing(s) filed on 20 November 2003 is Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction. The path or declaration is objected to by the limitation of the specific path of the specific pa	s/are: a) ☐ accepted or b) ☒ object ne drawing(s) be held in abeyance. Se ection is required if the drawing(s) is ob	ee 37 CFR 1.85(a). ojected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 					
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date	4) Interview Summar Paper No(s)/Mail D 5) Notice of Informal 6) Other:				

Claims 1-7 are objected to because of the following informalities:

The term "predetermined" in claim 1 is a relative term, which renders the claim indefinite. The term "predetermined" is not defined by the claim, the specification does not provide a standard for ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention. If applicant intends a particular process, it should be clearly recited.

In claim 1, line 17, "a" before "top face", should be replaced with --the--.

Appropriate correction is required.

The drawings are objected to as failing to comply with 37 CFR 1.84(p)(4) because reference character "132" has been used to designate both second photoresist pattern and conductive layer. Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The replacement sheet(s) should be labeled "Replacement Sheet" in the page header (as per 37 CFR 1.84(c)) so as not to obstruct any portion of the drawing figures. If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1 and 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over applicant's admitted prior art, in combination with DeBar et al (US 2004/0041884 A1).

Applicant's admitted prior art discloses the following:

- a) preparing a semiconductor substrate 110 obtained by a process (Figure 1B);
- b) forming a sacrificial layer 130 on the semiconductor substrate (Figure 1C);
- c) forming photoresist pattern on the sacrificial layer (Figure 1C);
- d) etching the sacrificial layer by using the photoresist pattern as an etching mask, thereby forming an opening 131 (Figure 1D);
- e) depositing conductive 132 layer on sides and a bottom face of the opening and a top face of the sacrificial layer (Figure 1E);
- f) forming a photoresist 134 on the conductive layer, wherein a concave region of the conductive layer is completely filled with the photoresist (Figure 1E);
- g) planarizing the conductive layer till the top surface of the sacrificial layer is exposed (Figure F); and
- h) forming a bottom electrode 132A with cylindrical shape by removing the sacrificial layer enclosing the bottom electrode by using a wet process using buffered oxide etchant (BOE) or hydrogen fluoride (HF), and by removing a residual photoresist (Figure 1G, and Page 5, second full paragraph).

Applicant's admitted prior art does not disclose removing the sacrificial layer by using an O₂ plasma. DeBar et al discloses removal of sacrificial layers by either using hydrogen fluoride,

and/or an O₂ plasma (Paragraph 0089). It would have been within the scope of one of ordinary skill in the art to combine the teachings of applicant's admitted prior art and DeBar et al, to enable the step of forming sacrificial layer 130 to be performed, by employing either of the materials and processes disclosed by DeBar et al.

Claims 2-6 would be allowable if rewritten to overcome the objection(s) set forth in this Office action and to include all of the limitations of the base claim and any intervening claims.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Joannie García whose telephone number is (571) 272-1861. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571) 272-1855. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

George Fourson
Primary Examiner
Art Unit 2823

JAG

December 10, 2004

GFourson Primary Examiner